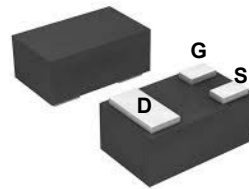
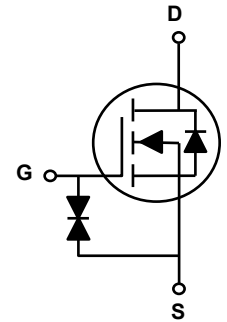


Main Product Characteristics

V_{DS}	20V
$R_{DS(ON)}$	230m Ω
I_D	1.4A



SOT-883



Schematic Diagram

Features and Benefits

- Advanced MOSFET process technology
- Ideal for high efficiency switched mode power supplies
- Low on-resistance with low gate charge
- Fast switching and reverse body recovery



Description

The GSFW0202 utilizes the latest techniques to achieve high cell density and low on-resistance. These features make this device extremely efficient and reliable for use in high efficiency switch mode power supply and a wide variety of other applications.

Absolute Maximum Ratings (T_J=25°C unless otherwise specified)

Parameter	Symbol	Max.	Unit
Drain-Source Voltage	V_{DSS}	20	V
Gate-Source Voltage	V_{GSS}	±8	V
Drain Current-Continuous ^{1,3} (T _A =25°C)	I_D	1.4	A
Drain Current-Continuous ^{1,3} (T _A =70°C)		1.1	
Drain Current-Pulsed ²	I_{DM}	3.5	A
Diode Continuous Forward Current	I_S	0.6	A
Power Dissipation(T _A =25°C)	P_D	0.7	W
Power Dissipation(T _A =70°C)		0.4	
Thermal Resistance, Junction-to-Ambient ²	$R_{\theta JA}$	180	°C/W
Storage Temperature Range	T _{STG}	-55 To +150	°C
Operating Junction Temperature Range	T _J	-55 To +150	°C

Electrical Characteristics ($T_J=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=250\mu A$	20	-	-	V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=16V, V_{GS}=0V$	-	-	1	μA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_{DS}=250\mu A$	0.5	-	1	V
Gate-Source Leakage Current	I_{GSS}	$V_{GS}=\pm 8V, V_{DS}=0V$	-	-	± 10	μA
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=4.5V, I_D=0.55A$	-	190	230	m Ω
		$V_{GS}=2.5V, I_D=0.45A$	-	234	305	
		$V_{GS}=1.8V, I_D=0.35A$	-	303	455	
Forward Transconductance	g_{fs}	$V_{DS}=5V, I_D=0.55A$	-	1.7	-	S
Total Gate Charge	Q_g	$V_{DS}=10V, I_D=1A, V_{GS}=2.5V$	-	1.1	-	nC
Total Gate Charge	Q_g	$V_{DS}=10V, I_D=1A, V_{GS}=4.5V$	-	2	-	nC
Gate-Source Charge	Q_{gs}		-	0.3	-	
Gate-Drain Charge	Q_{gd}		-	0.3	-	
Turn-On Delay Time	$t_{d(on)}$	$V_{DS}=10V, R_{GEN}=6\Omega, V_{GS}=4.5V, I_D=2A$	-	1.2	-	nS
Turn-On Rise Time	t_r		-	25	-	
Turn-Off Delay Time	$t_{d(off)}$		-	14	-	
Turn-Off Fall Time	t_f		-	15	-	
Input Capacitance	C_{iss}	$V_{DS}=10V, V_{GS}=0V, F=1MHz$	-	43	-	pF
Output Capacitance	C_{oss}		-	9	-	
Reverse Transfer Capacitance	C_{rss}		-	6	-	
Reverse Diode Characteristics						
Diode Forward Voltage	V_{SD}	$V_{GS}=0V, I_{SD}=0.35A$	-	-	1.1	V
Reverse Recovery Time	t_{rr}	$I_F=1A, di/dt=100A/\mu s$	-	9	-	nS
Reverse Recovery Charge	Q_{rr}		-	1	-	nC

Note :

1. The value of $R_{\theta JA}$ is measured with the device mounted on 1in2 FR-4 board with 2oz. Copper, in a still air environment with $T_A=25^{\circ}\text{C}$. The value in any given application depends on the user's specific board design.
2. Repetitive rating, pulse width limited by junction temperature .
3. The current rating is based on the $t<10s$ junction to ambient thermal resistance rating.

Typical Electrical and Thermal Characteristic Curves

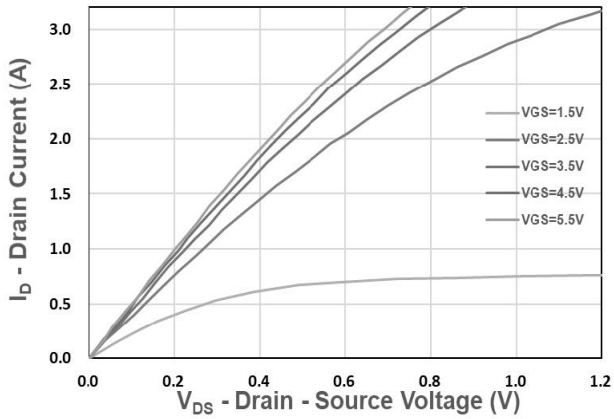


Figure 1. Output Characteristics

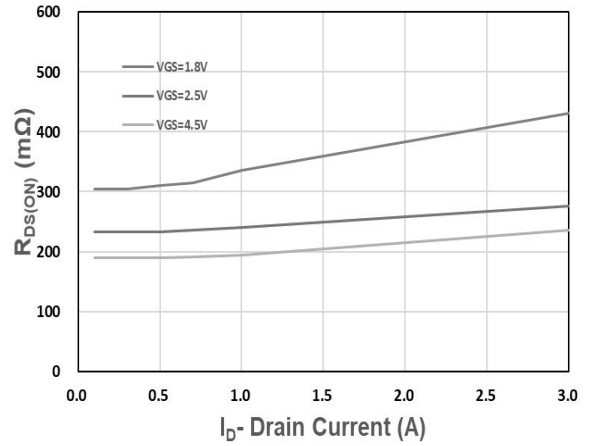


Figure 2. On-Resistance vs. I_D

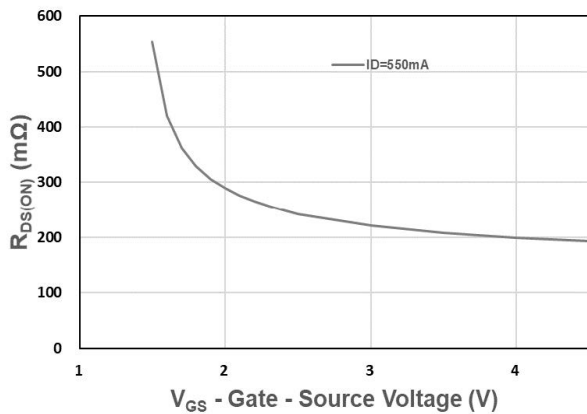


Figure 3. On-Resistance vs. V_{GS}

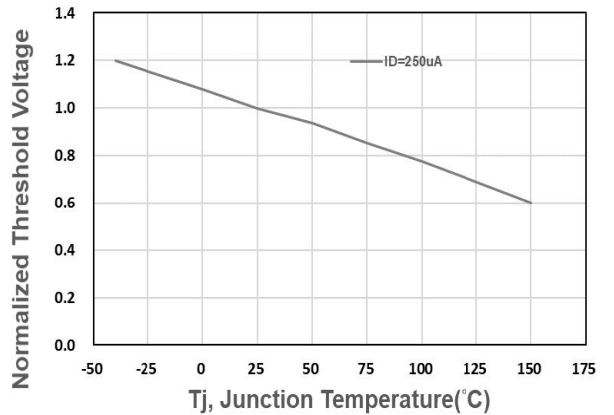


Figure 4. Gate Threshold Voltage

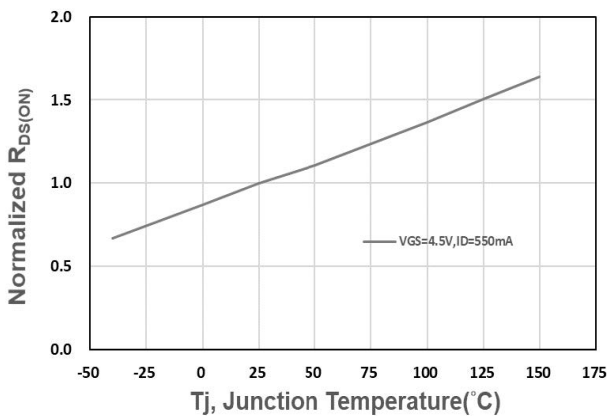


Figure 5. Drain-Source On Resistance

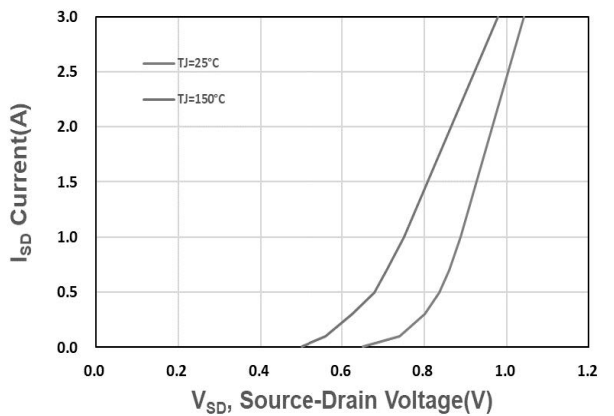


Figure 6. Source-Drain Diode Forward

Typical Electrical and Thermal Characteristic Curves

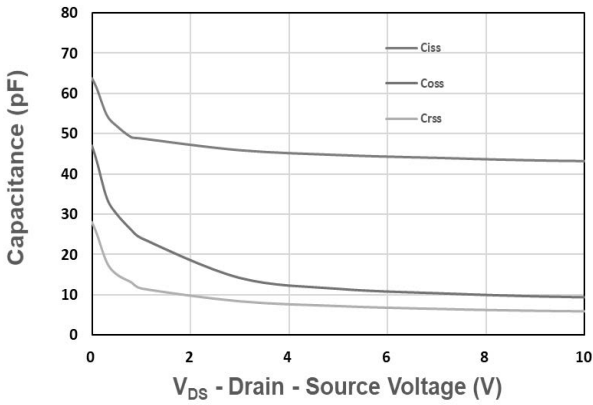


Figure 7. Capacitance

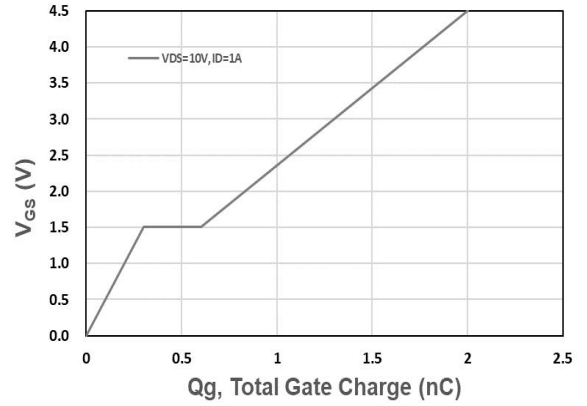


Figure 8. Gate Charge Characteristics

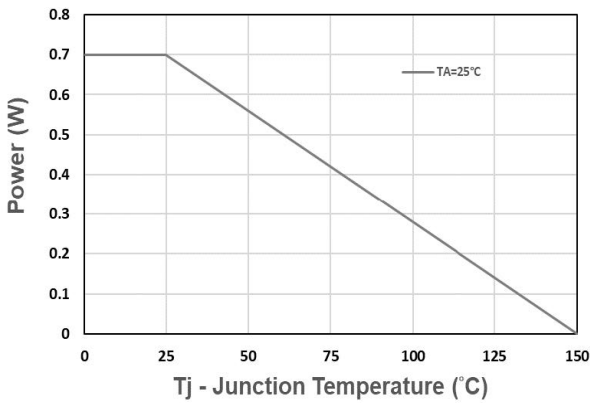


Figure 9. Power Dissipation

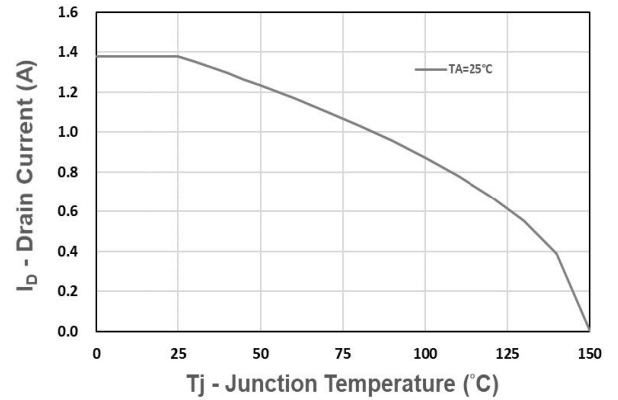


Figure 10. Drain Current

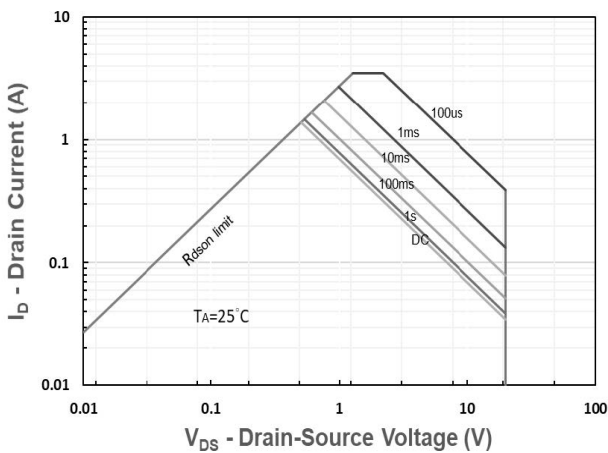


Figure 11. Safe Operating Area

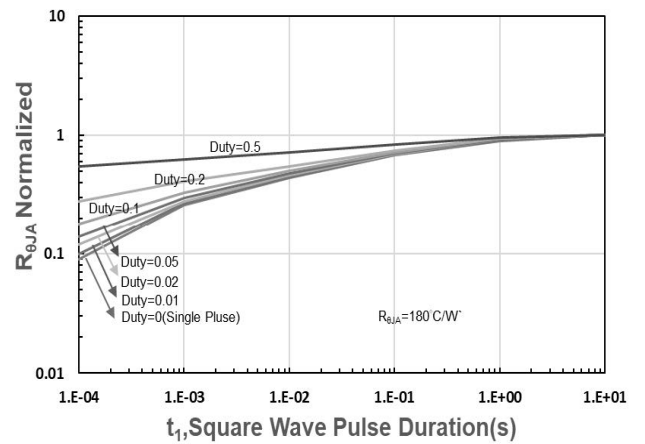
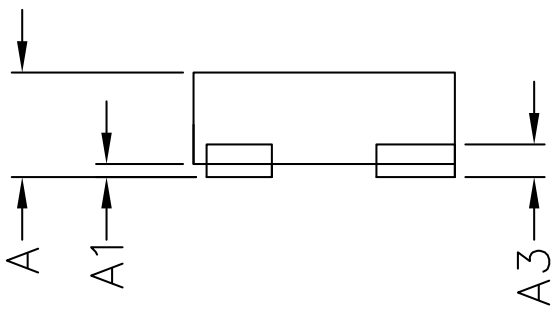
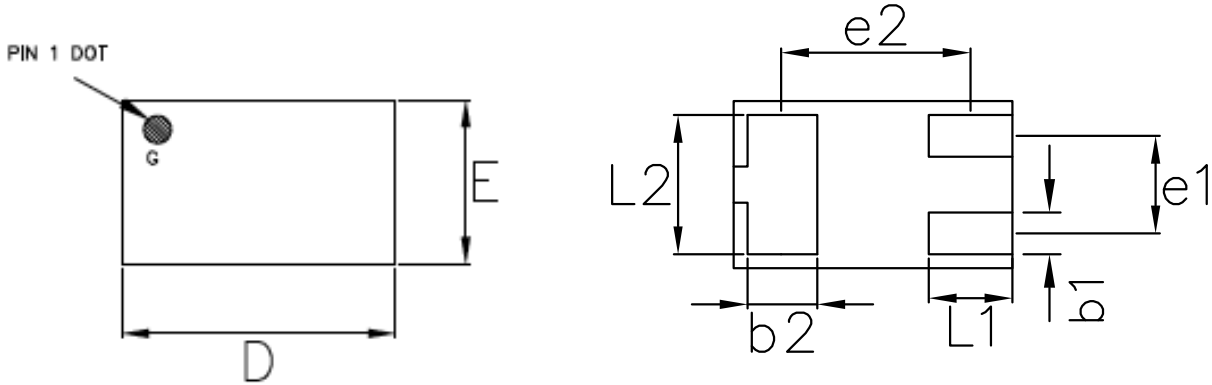


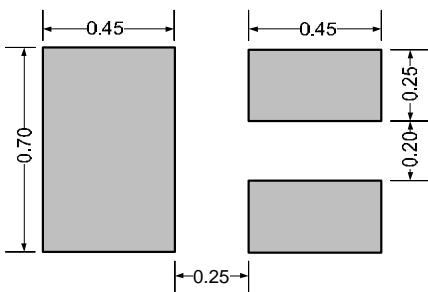
Figure 12. $R_{\theta JA}$ Transient Thermal Impedance

Package Outline Dimensions (SOT-883)



Package Outline Dimensions (MM)			
Package	SOT-883		
REF.	MIN.	TYP.	MAX
A	0.40	-	0.50
A1	0.001	-	0.05
A3	0.125 REF.		
D	0.95	1.00	1.05
E	0.55	0.60	0.65
b1	0.10	0.15	0.20
b2	0.20	0.25	0.30
L1	0.20	0.30	0.40
L2	0.40	0.50	0.60
e1	0.35 BSC		
e2	0.675 BSC		

Recommended Pad Layout



(Unit in MM)

Order Information

MPN	Package	Marking Code	Carrier	Quantity	HSF Status
GSFW0202	SOT-883	48	Tape & Reel	10000/Reel	RoHS Compliant